



OCTAL D-TYPE FLIP-FLOP WITH 3 STATE OUTPUTS

Description

The 74LVC374A provides eight edge-triggered D-type flip-flops featuring 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. These devices are particularly suitable for implementing buffer registers, input/output (I/O) ports, bidirectional bus drivers, and working registers. On the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels set up at the data (D) inputs. A buffered output-enable $\overline{(OE)}$ input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components. \overline{OE} does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

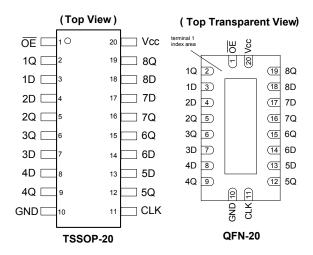
The '374A is functionally identical to the '574A, but the '574 has a different pin arrangement.

The device is designed for operation with a power supply range of 1.65V to 3.6V. The device is fully specified for partial power down applications using I_{OFF} .

Features

- Supply Voltage Range from 1.65V to 3.6V
- Sinks or Sources 24ma at V_{CC} = 3V
- CMOS Low Power Consumption
- I_{OFF} Supports Partial Power Down Operation
- Inputs or Outputs Accept Up to 5.5V
- Inputs Can Be Driven by 3.3V or 5V Allowing for Mixed Voltage Applications
- Schmitt Trigger Action at All Inputs
- Typical V_{OLP} (Quiet Output Ground Bounce) Less Than 0.8V with V_{CC} = 3.3V and T_A = +25°C
- Typical V_{OHV} (Quiet Output dynamic VOH) Greater than 2.0V with V_{CC} = 3.3V and T_A = +25°C
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
 - Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 250mA per JESD 78, Class I
- All devices are:
 - Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
 - Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

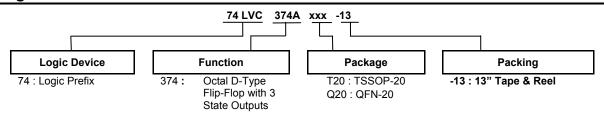
- General Purpose Logic
- Bus Driving
- Power Down Signal Isolation
- Wide array of products such as:
 - PCs, Notebooks, Netbooks, Ultrabooks
 - Networking Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Ordering Information



Part Number	Package	Package	Package	13" Tape	and Reel
Part Number	Code	(Note 4 & 5)	Size	Quantity	Part Number Suffix
74LVC374AT20-13	T20	TSSOP-20	6.4mm X 6.5mm X 1.2mm 0.65 mm lead pitch	2500/Tape & Reel	-13
74LVC374AQ20-13	Q20	V-QFN4525-20	2.5mm X 4.5mm X 0.95mm 0.50 mm lead pitch	2500/Tape & Reel	-13

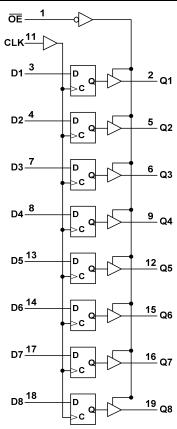
Notes:

- 4. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 5. V-QFN4525-20 is a JEDEC recognized naming convention that specifies the package thickness category as V and the number 4525 describes the package as 4.5mm X 2.5mm.

Pin Descriptions

Number Name			
2 Q1 Latch Output 3 D1 Data Input 4 D2 Data Input 5 Q2 Latch Output 6 Q3 Latch Output 7 D3 Data Input 8 D4 Data Input 9 Q4 Latch Output 10 GND Ground 11 CLK Clock 12 Q5 Latch Output 13 D5 Data Input 14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input			Description
3 D1 Data Input 4 D2 Data Input 5 Q2 Latch Output 6 Q3 Latch Output 7 D3 Data Input 8 D4 Data Input 9 Q4 Latch Output 10 GND Ground 11 CLK Clock 12 Q5 Latch Output 13 D5 Data Input 14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input 17 D7 Data Input 18 D5 Data Input 19 D5	1	ŌĒ	Output Enable
4 D2 Data Input 5 Q2 Latch Output 6 Q3 Latch Output 7 D3 Data Input 8 D4 Data Input 9 Q4 Latch Output 10 GND Ground 11 CLK Clock 12 Q5 Latch Output 13 D5 Data Input 14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input	2	Q1	Latch Output
5 Q2 Latch Output 6 Q3 Latch Output 7 D3 Data Input 8 D4 Data Input 9 Q4 Latch Output 10 GND Ground 11 CLK Clock 12 Q5 Latch Output 13 D5 Data Input 14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input	3	D1	Data Input
6 Q3 Latch Output 7 D3 Data Input 8 D4 Data Input 9 Q4 Latch Output 10 GND Ground 11 CLK Clock 12 Q5 Latch Output 13 D5 Data Input 14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input 17 D7 Data Input 18 D8	4	D2	Data Input
7 D3 Data Input 8 D4 Data Input 9 Q4 Latch Output 10 GND Ground 11 CLK Clock 12 Q5 Latch Output 13 D5 Data Input 14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input	5	Q2	Latch Output
8 D4 Data Input 9 Q4 Latch Output 10 GND Ground 11 CLK Clock 12 Q5 Latch Output 13 D5 Data Input 14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input	6	Q3	Latch Output
9 Q4 Latch Output 10 GND Ground 11 CLK Clock 12 Q5 Latch Output 13 D5 Data Input 14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input 19 Data Input	7	D3	Data Input
10 GND Ground 11 CLK Clock 12 Q5 Latch Outpu 13 D5 Data Input 14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input	8	D4	Data Input
11 CLK Clock 12 Q5 Latch Outpu 13 D5 Data Input 14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input	9	Q4	Latch Output
12 Q5 Latch Output 13 D5 Data Input 14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input	10	GND	Ground
13 D5 Data Input 14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input	11	CLK	Clock
14 D6 Data Input 15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input	12	Q5	Latch Output
15 Q6 Latch Output 16 Q7 Latch Output 17 D7 Data Input	13	D5	Data Input
16 Q7 Latch Output 17 D7 Data Input	14	D6	Data Input
17 D7 Data Input	15	Q6	Latch Output
	16	Q7	Latch Output
18 D8 Data Input	17	D7	Data Input
To Do Data Input	18	D8	Data Input
	19	Q8	Latch Output
20 Vcc Supply Volta	20	Vcc	Supply Voltage

Logic Diagram



Function Table

	(Each Latch)							
	INPUTS	3	OUTPUT					
OE	CLK	D	Q					
L	↑	Н	Н					
L	↑	L	L					
L	H or L	Х	Q_0					
Н	Х	Х	Z					



Absolute Maximum Ratings (Notes 6 & 7)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
I _{IK}	Input Clamp Current V _I < 0V	-20	mA
lok	Output Clamp Current V _O < 0V	-50	mA
Io	Continuous Output Current -0.5V < V _O V _{CC} +0.5V	±50	mA
Icc	Continuous Current Through V _{CC}	100	mA
I _{GND}	Continuous Current Through GND	-100	mA
T _J	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Notes:

- 6. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
- 7. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

Recommended Operating Conditions (Note 8)

Symbol	Parameter	Conditions	Min	Max	Unit	
M	Cumply Voltage	Operating	1.65	3.6	V	
V_{CC}	Supply Voltage	Data Retention Only	1.5	_	V	
VI	Input Voltage	_	0	5.5	V	
Vo	Output Voltage	_	0	V _{CC}	V	
		V _{CC} = 1.65V	_	-4		
	I light Lavel Output Compant	Lligh Lavel Output Current	V _{CC} = 2.3V	_	-8	A
Іон	High-Level Output Current	V _{CC} = 2.7V	_	-12	mA	
		V _{CC} = 3.0V	_	-24		
		V _{CC} = 1.65V	_	4		
	Land and Ortant Orman	V _{CC} = 2.3V	_	8		
loL	Low-Level Output Current	V _{CC} = 2.7V	_	12	mA mA	
		V _{CC} = 3.0V	_	24]	
Δt/ΔV	Input Transition Rise or Fall Rate		_	10	ns/V	
T _A	Operating Free-Air Temperature		-40	+125	°C	

Note:

8. Unused inputs should be held at V_{CC} or ground.



Electrical Characteristics

Symbol	Parameter	Test Condi	tions	V _{cc}	T _A = -40°C	C to +85°C	T _A = +85°C	to +125°C	Unit
Symbol	Parameter	rest Condi	tions	Vcc	Min	Max	Min	Max	Unit
				1.65V to 1.95V	V _{CC} X 0.65	_	V _{CC} X 0.65	_	
V_{IH}	High-Level Input Voltage			2.3V to 2.7V	1.7	_	1.7	_	V
	Voltage			3.0V to 3.6V	2	_	2	_	
				1.65V to 1.95V	_	V _{CC} X 0.35	_	V _{CC} X 0.35	
V_{IL}	Low-Level input voltage			2.3V to 2.7V	_	0.7	_	0.7	V
	Voltage			3.0V to 3.6V	_	0.8	_	0.8	
		$I_{OH} = -50 \mu A$		1.65V to 3.6V	V _{CC} -0.2	_	V _{CC} -0.3	_	
		$I_{OH} = -4mA$		1.65V	1.2	_	1.05	_	
V	High-Level Output	$I_{OH} = -8mA$		2.3V	1.7	_	1.65	_	
V_{OH}	Voltage	I = 12m A		2.7V	2.2	_	2.05	_	V
		I _{OH} = -12mA		3.0V	2.4	_	2.48	_	V
		I _{OH} = -24mA		3.0V	2.3	_	2.0	_	
		$I_{OL} = 100 \mu A$		1.65V to 3.6V	_	0.2	_	0.3	
		I _{OL} = 4mA		1.65V	_	0.45	_	0.65	
V_{OL}	Low-Level Output Voltage	I _{OL} = 8mA		2.3V	_	0.60	_	0.80	V
	Voltage	I _{OL} = 12mA		2.7V	_	0.40	_	0.60	
		I _{OL} = 24mA		3.0V	_	0.55	_	0.80	
I _{OFF}	Power Down Leakage Current	V_1 or $V_0 = 0$ or 5	.5V	0V	_	±10	_	20	μΑ
l _l	Input Current Control Pins	V _I =GND or 5.5V	,	0 to 3.6V	_	±5	_	± 20	μΑ
l _{OZ}	Z-State Current Including Input Current I/O Pins	V _I = GND or 5.5V V _O = 0 to 5.5V		3.6V	_	±5	_	± 20	uA
I _{cc}	Supply Current	$V_1 = GND \text{ or } V_{CC}$ $I_O = 0$		3.6V	_	10	_	40	μΑ
ΔI_{CC}	Additional Supply Current	One input at V _{CC} lo = 0A	-0.6V	2.7V to 3.6V		500	_	5000	μΑ
Ci	Input Capacitance		V _I = GND or V _{CC}	0V to 3.6V		/pical /pical	4.0 ty 5.5 ty		pF



Switching Characteristics

Cumbal	Parameter	Test	· · ·		T _A = +25°(3	-40°C t	o +85°C	+85°C t	o +125°C	Unit	
Symbol	Parameter	Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit	
			1.8V ± 0.15V	35	40		35		30			
f _{MAX}	Maximum	Figure 1	2.5V ± 0.3V	50	60		50		45		Mhz	
IMAX	Frequency		2.7V	80	100		80		64		IVIIIZ	
			3.3V ± 0.3V	100	125		100		80			
			1.8V ± 0.15V	5.0	2.5		5.0		5.5			
	Pulse Width	Figure 1	2.5V ± 0.3V	4.0	2.0		4.0		4.5		20	
t _W	CLK		2.7V	3.3	1.7		3.3		3.5		ns	
			3.3V ± 0.3V	3.0	1.5		3.0		3.5			
			1.8V ± 0.15V	4.0	2.0		4.0		4.5			
	Set-up Time D _N	Figure 1	2.5V ± 0.3V	3.0	1.5		3.0		3.5			
t _{su}	to CLK		2.7V	2.0	1.0		2.0		2.5		ns	
			3.3V ± 0.3V	2.0	1.0		2.0		2.5			
			1.8V ± 0.15V	3.0	1.5		3.0		3.5			
	Hold Time	me Figure 1	2.5V ± 0.3V	2.0	1.0		2.0		2.5			
t _H	t _H D _N to CLK	D _N to CLK		2.7V	1.5	1.0		1.5		2.0		ns
			$3.3V \pm 0.3V$	1.5	1.0		1.5		2.0			
			1.8V ± 0.15V	1	6	12.2	1	13.5	1	16.9		
4	Propagation	Figure 1	2.5V ± 0.3V	1	3.9	8.5	1	9.0	1	8.7		
t _{PD}	Delay CLK to Q _N		2.7V	1	4.2	7.8	1	8.1	1	9.5	ns	
	OLIVIO QN		3.3V ± 0.3V	1.5	3.8	6.8	1.5	7.0	1.5	8.0		
			1.8V ± 0.15V	1	7.8	16.5	1	17	1	14.2		
4	Enable Time	Figure 1	2.5V ± 0.3V	1	4	9	1	9.5	1	8.2		
t _{EN}	OE to Q _N	rigure i	2.7V	1	4.4	8.3	1	8.5	1	10.0	ns	
			3.3V ± 0.3V	1.7	4.1	7.3	1.7	7.5	1.7	9.0		
			1.8V ± 0.15V	1	7.8	16.5	1	17	1	14.2		
	Disable Time	Figure 1	2.5V ± 0.3V	1	4	9	1	9.5	1	8.2	20	
t _{DIS}	OE to Q _N	Figure 1	2.7V	1	4.4	8.3	1	8.5	1	10.0	ns	
		3.3V ± 0.3V	1.7	4.1	7.3	1.7	7.5	1.7	9.0			
			1.8V ± 0.15V	1	7.8	16.5	1	17	1	14.2		
	Disable Time	F: 1	2.5V ± 0.3V	1	4	9	1	9.5	1	8.2	no	
t _{DIS}	\overline{OE} to Q_N		2.7V	1	4.4	8.3	1	8.5	1	10.0	ns	
			$3.3V \pm 0.3V$	1.7	4.1	7.3	1.7	7.5	1.7	9.0		
tsk(0)	Output Skew Time		3.3V ± 0.3V			1.0				1.5	ns	

Operating Characteristics

 $T_A = +25^{\circ}C$

Symbol	Parameter	Test Conditions	V _{cc}	Тур	Unit	
	Dower dissination	F = 10 MHz	1.8V± 0.15V	9.9		
C_{pd}	Power dissipation capacitance per gate	Outputs Enabled		2.5V± 0.3V	10.2	pF
	capacitance per gate		3.3V± 0.3V	10.6		

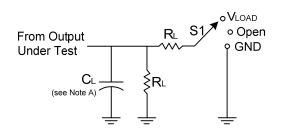
Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
θ_{JA}	Thermal Resistance Junction-to-Ambient	TSSOP-20	(Note 9)	_	74	_	°C/W
θ _{JC}	Thermal Resistance Junction-to-Case	TSSOP-20	(Note 9)	_	15	_	°C/W
θ_{JA}	Thermal Resistance Junction-to-Ambient	V-QFN4525-20	(Note 9)	_	67	_	°C/W
θις	Thermal Resistance Junction-to-Case	V-QFN4525-20	(Note 9)	_	20	_	°C/W

Note: 9. Test conditions for TSSOP-20 and V-QFN4525-20: Devices mounted on 4 layer FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout per JESD 51-7.

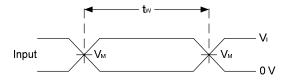


Parameter Measurement Information

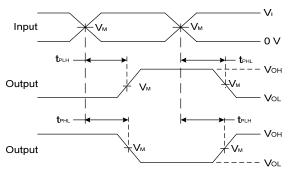


TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V_{LOAD}
t _{PHZ} /t _{PZH}	GND

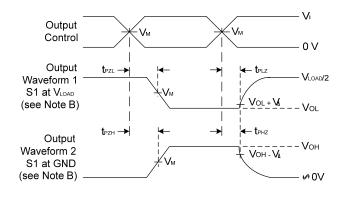
.,	In	Inputs		.,			
V _{cc}	Vı	t _r /t _f	V _M V _{LOAD}		CL	R _L	V Δ
1.8V ± 0.15V	V_{CC}	≤2ns	V _{cc} /2	2 x V _{CC}	30pF	1ΚΩ	0.15V
2.5V ± 0.2V	V_{CC}	≤2ns	V _{cc} /2	2 x V _{CC}	30pF	500Ω	0.15V
2.7V	2.7V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V
$3.3V \pm 0.3V$	2.7V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V



Voltage Waveform Pulse Duration



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times Low and High Level Enabling

- Notes:
 - A. Includes test lead and test apparatus capacitance. B. All pulses are supplied at pulse repetition rate \leq 10 MHz.
 - C. Inputs are measured separately one transition per measurement. D. t_{PLZ} and t_{PHZ} are the same as $t_{\text{dis.}}$

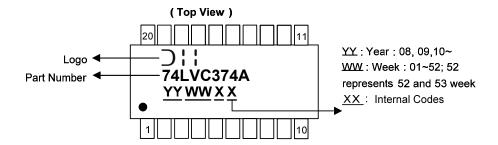
 - E. t_{PZL} and t_{PZH} are the same as t_{EN0}
 - F. t_{PLH} and t_{PHL} are the same as t_{PDL}

Figure 1 Load Circuit and Voltage Waveforms



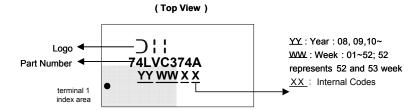
Marking Information

(1) TSSOP20



Part Number	Package
74LVC374AT20	TSSOP-20

(2) QFN-20 (V-QFN4525-20)



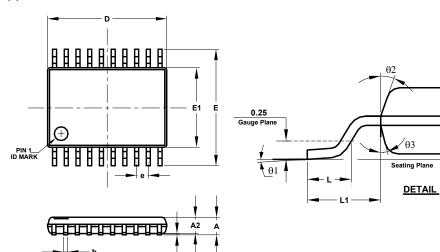
Part Number	Package
74LVC374AQ20	V-QFN4525-20



Package Outline Dimensions (All Dimensions in mm)

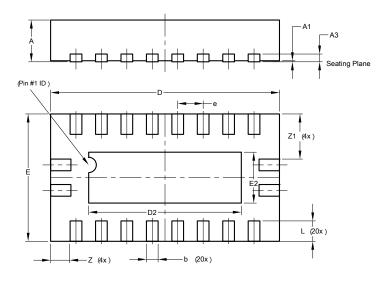
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(1) TSSOP-20



TSSOP-20				
Dim	Min	Max	Тур	
Α	-	1.20	-	
A1	0.05	0.15	-	
A2	0.80	1.05	-	
b	0.19	0.30	-	
С	0.09	0.20	-	
D	6.40	6.60	6.50	
Е	6.20	6.60	6.40	
E1	4.30	4.50	4.40	
е	0.65 BSC			
L	0.45	0.75	0.60	
L1	1.0 REF			
θ1	0°	8°	-	
θ2	10°	14°	12°	
θ3	10°	14°	12°	
All Dimensions in mm				

(2) QFN-20 (V-QFN4525-20)



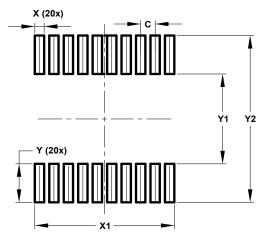
V-QFN4525-20				
Dim	Min	Max	Тур	
Α	0.75	0.85	0.80	
A1	0.00	0.05	0.02	
A3	-	-	0.15	
b	0.18	0.30	0.23	
D	4.45	4.55	4.50	
D2	2.85	3.15	3.00	
Е	2.45	2.55	2.50	
E2	0.85	1.15	1.00	
е	0.50BSC			
L	0.30	0.50	0.40	
Z	-	-	0.385	
Z 1	-	-	0.885	
All Dimensions in mm				



Suggested Pad Layout

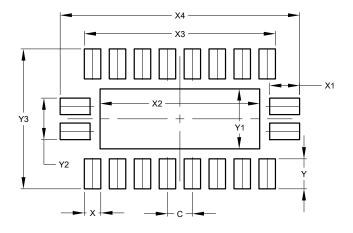
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) TSSOP-20



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	6.270
Υ	1.789
Y1	4.160
Y2	7.720

(2) QFN-20 (V-QFN4525-20)



Dimensions	Value (in mm)
С	0.500
Х	0.330
X1	0.600
X2	3.200
Х3	3.830
X4	4.800
Υ	0.600
Y1	1.200
Y2	0.830
V3	2 800



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 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

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